Photoinduced insulator-to-metal transition and surface statistics of VO$_2$ monitored by elastic light scattering

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compiled: December 2, 2014

Measurements of ultrafast light scattering within hemisphere are performed for statistical analysis of nonequilibrium processes in VO$_2$ epitaxial film. A Gerchberg-Saxton error reduction algorithm is applied for accurate calculation of surface autocorrelation function from light scattering data and for partial reconstruction of power spectral density function. Upon ultrafast photoinduced phase transition of VO$_2$, the elastic light scattering reveals anisotropic grain-size-dependent dynamics. It was found that the transition rate depends on the optical absorption and orientation of VO$_2$ grains with respect to polarization of the pump pulse. An observed stepwise evolution of surface autocorrelation length and transient anisotropy of scattering field presumably originate from complex multistage transformation of VO$_2$ lattice on subpicosecond time scale.

OCIS codes: (320.7130) Ultrafast processes in condensed matter, including semiconductors; (240.3695) Linear and nonlinear light scattering from surfaces; (290.1483) BSDF, BRDF, and BTDF; (190.5330) Photorefractive optics; (100.0118) Imaging ultrafast phenomena.

http://dx.doi.org/10.1364/XX.99.099999

1. Introduction
Vanadium dioxide is a promising photorefractive material for modern optoelectronics [1–4]. Upon heating, uniaxial stress, electron injection or light illumination VO$_2$ undergoes a first-order insulator-to-metal phase transition (I-M PT) with considerable change of elastic, structural, electronic and optical properties. The first observation of photoinduced PT in VO$_2$ was performed by Roach et al. [5]. While the thermally induced PT occurs at near room temperature $T_c$=341 K [6], the light-induced transition is nonthermal and can be initiated on an ultrafast time scale at temperature significantly below $T_c$ [7–9].

The light-induced PT dynamics of VO$_2$ is a complex process which involves many degrees of freedom. It depends on film morphology, strain, structural defects, external electric field, incident light polarization, wavelength, pulse duration and intensity [10–16]. VO$_2$ nanoparticles and nanocrystalline films show size-dependent transition dynamics [17–20]. The ultrafast insulator-to-metal phase transition of nanocrystalline films occurs within 130 fs at sufficiently high laser excitation, while at lower excitation the transition becomes much slower and takes tens of picoseconds. It was shown previously [21, 22] that the slow component of PT within ~100-300 ps can be related to a competitive process between thermal relaxation and phonon interaction with cooperative photoexcited electronic states. The PT threshold can be decreased by introducing Au nanoparticles in a VO$_2$ matrix due to surface-plasmon-polariton field enhancement and hot-electron injection from Au to VO$_2$ [23, 24]. Optical excitation can produce a metastable state [19, 25], specific transient [7, 12, 15, 26] or monoclinic metal-like state of VO$_2$ at high pressure [27]. Recent findings on ultrafast phonon dynamics [15] show that the laser excitation does not produce significant softening of phonon modes before the PT. Instead, the first-order PT occurs due to prompt change of the lattice potential.

Ultrafast light-induced PT is driven by nonequilibrium photoexcited electronic states, but the exact mechanism of the PT is still not fully understood. Several models have been proposed to explain this phenomenon. The general characteristics of phonon dynamics during PT were discussed by Cavalleri et al. [28], Kübler et al. [8], Semenov [29], Hada et al. [25] and recently by van Veenendaal [30] and Appavoo et al. [23]. These authors pointed out that photoexcited electrons can modify the vibrational spectrum of VO$_2$ and provide conditions for the PT. The main features of the PT dynamics on different time scales can also be explained in terms of ultrafast charge-transfer and vibronic relaxation of photoexcited
states [14, 31].

The problem of understanding the thermal and light-induced PT of VO₂ is aggravated by numerous conflicting experimental data. In some cases, thermal and nonlinear optical properties vary significantly from sample to sample. To date, the most reliable data were obtained for single crystal nanorods, nanobeams and nanoplatelets. Along with single crystal VO₂ , the information about PT dynamics of epitaxial and polycrystalline VO₂ films is of special interest, since these films represent different stochastic or highly ordered model systems with different morphology and concentration of structural defects. It is expected that the interaction between carriers via vibronic phonon mode and carrier-induced screening of the on-site Coulomb interactions in VO₂ plays a significant role in PT [30–34], and these processes are strongly dependent on film structure. The role of electron-electron correlations, electron-phonon and electron-surface scattering in VO₂ grains of different sizes can be a crucial issue in the phase transition and other relaxation processes. Therefore, special experimental methods are required in order to observe multiscale structural dynamics.

In this paper, angle-resolved ultrafast elastic light scattering technique was applied to obtain information about power spectral density (PSD), fractal dimension and autocorrelation function (ACF) of the VO₂ surface far from equilibrium. Precise calculation of ACF and partial reconstruction of PSD data was performed using the Gerchberg-Saxton algorithm [35, 36]. The ultrafast angle-resolved light scattering experiment opens a new possibility for the detection of mesoscale phase transformation and reveals anisotropic grain-size-dependent behavior. It has been observed that the characteristic transition time τ for crystalline film depends on polarization of the laser pump and noticeably increases for grains with sizes d < 530 nm. Numerical analysis shows that the size-dependence and anisotropy of the absorption coefficient can be the main origins which alter τ. The transient autocorrelation length (ACL) of the surface shows an abrupt rise only after a 270 fs delay with respect to the laser pump. A distinctive transient anisotropy of the scattering pattern appears as well after ~300 fs. This behavior is likely a consequence of the complex stepwise PT of VO₂.

2. Experimental Details
2.A. Measurements
Epitaxial 30-nm-thick film of vanadium dioxide with high phase purity was grown by pulsed laser deposition technique on r-cut sapphire (Al₂O₃) substrate. The light-induced PT dynamics of VO₂ on the mesoscale was studied with the scatterometer equipped by a femtosecond Spectra-Physics laser system shown in Fig. 1. This system consists of Ti:Sapphire oscillator and regenerative amplifier operating at wavelength λ=800 nm. Generated laser pulses are compressed down to 130 fs and split by a beamsplitter into pump and probe beams. The sample was mounted on the holder SH. The probe pulses were frequency-doubled by a 100 µm thick BBO crystal to the wavelength λ=400 nm, while the wavelength of pump radiation was λ=800 nm. The shorter probe wavelength allowed monitoring multi-scale surface structures with spatial frequencies up to f = 1/λ=2.5 µm⁻¹. Incident light was linearly polarized by a Glan-type prisms GP and GP’. The polarization of pump pulse was controlled by half-wave plate λ/2 and GP, so the mutual orientation of electric field vectors of pump (⃗E₀) and probe (⃗Eₚ) pulses can be set parallel or orthogonal. In order to initiate the PT of VO₂ film, the pump pulse was focused to a spot size of 1.2 mm with average fluence of W=4.7 mJ/cm². The spot size of the probe pulse was less than 100 µm in order to ensure interrogation of only uniformly excited region of the sample. The intensity I₀ of probe beam was substantially reduced by neutral density filter to eliminate any nonlinear interaction of this beam with the sample. Scattered light within hemisphere was projected to charge-coupled device (CCD) by elliptical mirror. This part of the optical setup was designed in accordance with the description given in Ref. 37. A color filter F installed at the front of the objective Ob transmitted the probe light and blocked the leak of the pump radiation onto the CCD camera. The temporal delay t between pump and probe pulses was controlled by a motorized translation stage Opt.Del. equipped with a retroreflector.

The surface topography of the films was studied by atomic force microscope (AFM, Park Scientific Instruments, Autoprobe CP).

2.B. Scattering Data and Surface Statistics
The advantage of angle-resolved light scattering technique is its ability to obtain statistical information about surface irregularities of different sizes [38–41], since each scattering angle corresponds to specific spatial frequency of the surface f = 1/d = sinθ/λ, where θ is the polar scattering angle and d is the characteristic size of irregularities. The scattering images were recorded by a SBIG
CCD camera and stored in 765x510 pixel files. These data were used for calculation of bidirectional-scatter-distribution-function (BSDF), PSD function and for reconstruction of autocorrelation function of the surface. These functions reflect general statistical properties of the surface. The BSDF can be directly calculated from angle-resolution light scattering as

$$BSDF(\theta, \varphi) = \left(\frac{dI_{\text{scatt}}(\theta, \varphi)}{d\Omega}\right) \frac{1}{I_0 \cos \theta},$$  

where $I_0$ is the intensity of incident light, $dI_{\text{scatt}}$ is the intensity of light scattered into solid angle $d\Omega$, $\varphi$ is the azimuthal angle. In this work the BSDF indicatrices where obtained from experimental data with Eq.(1), and used for calculation of PSD of the surface roughness. The relation between BSDF measured at normal incidence and PSD is given as [41]

$$PSD(f) = \frac{\lambda^4 BSDF(f)}{16\pi^2 Q \cos \theta},$$  

where $Q$ is an optical factor which depends on light polarization, scattering angle and dielectric constants. $Q$-factor can be calculated using equations obtained by Elson [42–44]. The PSD function calculated from Eq.(2) represents the statistical distribution of surface roughness versus surface spatial frequency.

The information about correlation of surface irregularities can be obtained from the autocorrelation function

$$ACF(r) = \lim_{L \to \infty} \frac{1}{L} \int_{-L}^{L} z(r')z(r'+r)dr',$$  

where $r$ is the is the translation length in the surface plane, and $z(r)$ is the surface profile defined over an area $L$. At zero translation $ACF(0) = \delta^2$, where $\delta$ is rms roughness [41]. In this work we use the normalized autocorrelation functions $ACF_0 = ACF/\delta^2$, calculated from scattering data.

The Wiener-Khinchin theorem shows that the ACF is a Fourier transform of PSD

$$ACF(r) = \int_{-\infty}^{+\infty} PSD(f)e^{i2\pi fr}df.$$  

Despite this simple relation between ACF and PSD, the correct calculation of ACF from PSD can be significantly affected in practice by effective-bandwidth limits with the absence of PSD data at low spatial frequencies blocked by the sample holder as well as above the frequency $f_{\text{max}} = \sin 90^\circ / \lambda = 1/\lambda$ [41, 45, 46]. In most cases, absence of experimental data introduces significant artifacts in ACF. Therefore, correct calculation of ACF requires a reconstruction of PSD within regions where the experimental data are absent. One of the solutions is the extrapolation of PSD using an ‘ABC’ model [46]. However in the present work we apply the Gerchberg-Saxton error reduction (ER) algorithm [35, 36], which produces a more natural precise reconstruction of the ACF and PSD pair.

The $n$-th cycle of the ER algorithm can be written as

$$ACF_n^*(r) = FFT^{-1}\{PSD_n(f)\}$$

$$ACF_n(r) = \begin{cases} \text{Re}[ACF_n^*(r)] & \text{if } r \in S \\ 0 & \text{if } r \notin S \end{cases}$$

$$PSD_{n+1}(f) = FFT\{ACF_n(r)\}$$

$$PSD_{n+1}(f) = \begin{cases} PSD_{\text{obs}}(f) & \text{if } f \in f_{\text{obs}} \\ \text{Re}[PSD_{n+1}(f)] & \text{if } f \notin f_{\text{obs}} \text{, } \text{Re}[PSD_{n+1}(f)] \geq 0 \\ 0 & \text{otherwise} \end{cases}$$  

where $PSD_{\text{obs}}$ is the measured PSD function within $f_{\text{obs}}$ spatial frequencies, $S$ is the autocorrelation function’s support (i.e. area where ACF is nonzero), $ACF^*$ is the inverse fast Fourier transform $FFT^{-1}$ of the measured PSD with reconstructed part, $PSD^*$ is the direct fast Fourier transform $FFT$ of the reconstructed autocorrelation function.

The constraints in the ER algorithm are quite strong, since both ACF and PSD functions are real and hence the ACF phase is 0 or $\pi$. This provides reliable and relatively fast convergence to reproducible results. The progress of iterations was monitored with the real-space squared error

$$\xi^2 = \sum_{r \in S} |ACF_n^*(r)|^2$$  

The size of the support $S$ was chosen to be comparable with the size of probe beam so as to provide convergence with minimal $\xi^2$. A detailed description of the ER algorithm and its application to phase reconstruction and imaging can be found in Ref. 36. For the ACF computation, the combination of the ER with hybrid input-output (HIO) technique reduces algorithm stagnation. However, in most cases it was enough to apply only ER (5) in order to obtain a robust satisfactory reconstruction of the ACF and PSD Fourier transform pair. We note that the ER with HIO algorithm can also be used to retrieve the full phase map of light scattering field and reconstruct the surface profile from BSDF data.

3. Results and discussion

3.A. Transient Light Scattering and Structural Dynamics

The ultrafast studies of light-induced PT were performed for the VO$_2$/Al$_2$O$_3$ film with thickness below the penetration depth of the pump pulse (56 nm for the semiconducting phase). Therefore, optical excitation was produced uniformly across the film. This allowed suppressing some artifacts in the measured signal
related to strong absorption in VO$_2$. The AFM image of surface topography (Fig. 2) shows that the average size of VO$_2$ grains is $d \sim 250$ nm. Some grains are merged into larger structures with $d \gtrsim 500$ nm. The root-mean-square roughness of the surface calculated from AFM data is $\delta = 41$ Å. The r-cut Al$_2$O$_3$ substrate has a rectangular atomic lattice on the surface, and the VO$_2$ crystalline film is epitaxially oriented on this substrate with directions [010]$_{VO_2}$// [100]$_{Al_2O_3}$ and [001]$_{VO_2}$// [021]$_{Al_2O_3}$ [14, 47, 48]. This resulted in slight scattering anisotropy in respect to [010]$_{VO_2}$ ($b_m$) and [001]$_{VO_2}$ ($c_m$) directions (Fig. 3a).

![Fig. 2. AFM topography of VO$_2$ film. Right upper panel: 1.4×1.4 µm AFM image. Left upper panel: surface height distribution histogram. Lower panel: a cross-section of AFM image.](image)

The PSD function (Fig. 3b) for the VO$_2$ film in insulating phase was calculated using Elson equations for rough surface scattering [44]. The optical constants for these calculations were obtained from additional angular measurements of reflection coefficient and data fit for s- and p-polarization of incident light. The cross-section of scattering indicatrix at arbitrary direction shows that the BSDF for VO$_2$/Al$_2$O$_3$ is practically a scaled PSD function, as shown in Fig. 3c. This indicates that the correct information about statistical redistribution of surface inhomogeneities can be obtained from BSDF data. This 'scatter prediction' is valid for optically smooth surfaces with $\delta < \lambda/(4\pi)$, in accordance with the Rayleigh smooth-surface criterion [41]. The VO$_2$ film satisfies this requirement. Thus, qualitatively the BSDF($f$) is fairly close to PSD($f$) function and weak changes during the PT. We note that the information about surface statistics obtained from BSDF($f$) becomes very useful when the system is in nonequilibrium state, and the material optical constants are unknown or undergo small alterations.

The PSD($f$) function in a log–log graph (inset in Fig. 3c) reveals its fractal-like linear behavior. Thus, the PSD($f$) can be approximated by 2D power spectrum as

$$\text{PSD}(f) = \tilde{K}_n/f^{n+1},$$

where the $\tilde{K}_n$ and $n$ are fractal parameters [45, 49]. The Hausdorff-Besicovitch dimension is defined as $D = (5 - n)/2$. The parameters obtained for PSD of VO$_2$ film are $n=1$ and $D=2$, which correspond to the extreme fractal and indicate close-packed crystallites of rugged surface [50].

Fig. 3c shows a decrease of BSDF signal with time. However, the position of all diffraction peaks in scattering indicatrix remains the same within 1 ps. This fact is strong evidence that the surface geometry also remains the same. We note that the structural dynam-
ics upon light-induced PT substantially differs from the case of thermal transition where the VO$_2$ film undergoes twinning and domain formation accompanied by a shift of diffraction peaks with noticeable transformation of total scattering indicatrix [48]. The subpicosecond time scale is too short for long-range phonon interactions which could result in twinning or reorientation of VO$_2$ microcrystallites. The total switching into metallic phase occurs simultaneously and independently in different domains of the film. Only short-range interactions are considerable on the observed 1 ps time scale. This PT mechanism does not imply nucleus growth in metastable environment.

While the surface geometry of VO$_2$/Al$_2$O$_3$ film remains the same during the ultrafast PT, the lattice transformation from monoclinic M$_1$ to tetragonal R-phase changes the dielectric permittivity tensor. The alteration of dielectric constant $\Delta\varepsilon$ slightly changes the optical factor $Q$ in Eq.(2) and, as a result, the BSDF scattering indicatrix. For epitaxial VO$_2$ film the alteration of $\Delta\varepsilon$ and $Q$ is anisotropic [14]. Moreover, if $\Delta\varepsilon$ depends on particle size, it qualitatively modifies the PSD function of the surface versus $f$.

The contribution of $\Delta\varepsilon$ to the scattering indicatrix was observed from the transient change $\Delta$BSDF$(t)/$BSDF$(0)$, where $\Delta$BSDF$(t)=BSDF(t)-BSDF(0)$, for orthogonal ($\vec{E}_w \perp \vec{E}_o$, Fig. 4a) and parallel ($\vec{E}_w \parallel \vec{E}_o$, Fig. 4b) polarizations of pump and probe pulses. Indicatrices obtained for $\vec{E}_w \perp \vec{E}_o$ show some anisotropy which can be assigned to the photoinduced anisotropy of the $Q$-factor. However, changing the polarization of the pump pulse to $\vec{E}_w \parallel \vec{E}_o$ results in slightly different distribution of $\Delta$BSDF$(t)/$BSDF$(0)$ with higher level of isotropy. This result indicates that the polarization of pump pulse can be a critical parameter in PT dynamics. Independently on light polarization, a specific scattering pattern appears within $0^\circ < \theta < 60^\circ$. Thus, at $t > 600$ fs $\Delta$BSDF$(t)/$BSDF$(0) = -0.1$ in the central part of the indicatrix, but at $\theta > 60^\circ$ it changes to slightly anisotropic pattern with $\Delta$BSDF$(t)/$BSDF$(0) = 0.3$.

As shown in Fig. 2, the average size of the largest VO$_2$ grains is $d \sim 250$ nm which corresponds to $f = 4 \mu$m$^{-1}$. This spatial frequency is above the range attainable by the light scattering technique. On the other hand, some grains are merged into domains with $d \gtrsim 500$ nm, $f \lesssim 2 \mu$m$^{-1}$. Light scattering by these domains corresponds to $0^\circ < \theta < 55^\circ$ angular range which is very close to the range where the specific scattering pattern in Fig. 4 was observed. Therefore scattering within this angular rage is assigned to the light scattering by merged VO$_2$ grains.

The distinctive scattering pattern within $0^\circ < \theta < 60^\circ$ in Fig. 4 (see also Media 1) appears after $\sim 300$ fs due to grain-size-dependent structural PT. It is believed that the transient scattering signal at time $t \lesssim 300$ fs is related mostly to nonlinear response of the electronic subsystem via third-order optical nonlinearity. However, the screening of Coulomb correlations due to photoexcitation of free carriers can result in subsequent band gap renormalization with additional contribution to the first-order susceptibility on $\sim 300$ fs time-scale. The nature of such nonlinear dynamics requires additional studies.

We now turn our attention to the transient autocorrelation function of the surface. Optical constants of VO$_2$ in photoexcited state were unknown and, therefore, the calculation of PSD was not performed for I-M PT. On the other hand, for optically smooth VO$_2$ film the BSDF($f$) is nearly a scaled PSD($f$) function, as shown above (see Fig. 3c). Therefore we applied the 'scatter prediction' approximation, where the experimentally measured BSDF($f$) was used to describe the power spectral density of the surface. Thus, the surface autocorrelation function was calculated by Fourier transform of BSDF($f$) data. Temporal evolution of ACF$_s$ shows a relatively small change $\Delta$ACF$_s$ (Fig. 5a-c). The ACF$_s$
pattern during the light-induced PT remains almost the same. Such behavior is assigned to the transient evolution of VO$_2$ optical constants, but without film twinning or modification of surface relief.

Fig. 5. (a) Autocorrelation function of the surface (see Media 1). (b) Change of ACFs in photoexcited metallic state. (c) Cross-section of ACFs distribution at $\varphi=45^\circ$. (d) Transient autocorrelation length and light scattering signal integrated within hemisphere. Solid line is a sigmoidal fit.

Structural PT produces a change of the dielectric permittivity tensor, increasing the optical isotropy of the film in metallic R-phase [14]. As the film switches to metal, the symmetry of the VO$_2$ lattice increases and the amplitude of spatial oscillations of ACF$_s$ at $r > 1.0 \mu m$ slightly diminishes, as can be seen from the inset in Fig. 5c and the ΔACF$_s$ map in Fig. 5b. Moreover, the transient behavior of ΔACF$_s$ also demonstrated some temporal oscillations (see Media 1) associated with modulation of VO$_2$ optical constants by photoexcited coherent lattice vibrations [8, 15, 27, 51].

The transient change of the central maximum within $0 < r < 1.0 \mu m$ shows slight but well-resolved distinctive broadening during the PT (Fig. 5b,c). This maximum originates from statistically random distribution of surface irregularities and fluctuations of optical constants, and its broadening results in increase of the surface autocorrelation length within ΔACL= $4.2 \times 10^{-3} \mu m$ (Fig. 5d). Thus, the ACL increases abruptly after 270 fs delay, during 265 fs, due to increasing optical isotropy and homogeneity of the film.

The evolution of ACL differs from that of the integrated light scattering signal $I_{\text{scatt}}/I_0$, where the signal changes immediately as the laser pump pulse excites the sample (Fig. 5d). Such behavior of ACL can indicate a delay between the laser pump instant and a structural transformation of the VO$_2$ film. This result agrees with the transient dynamics of ΔBSDF(t)/BSDF(0) [Fig. 4] and with conclusions obtained in Refs. 15, 48, 52. It is believed that the photoinduced screening of the Coulomb potential reduces the dimerization of V ions during the first $\sim$300 fs and results in instability of the M$_{1}$-phase, with subsequent stepwise structural transition. It is important to note that the 300 fs time-scale is close to the characteristic time $\tau^* \simeq 120$ fs of the resonance phonon scattering on V-V dimers obtained in Ref. 19. This phonon scattering can be one of the parameters which control the resonance vibronic transition from an optically excited state in the insulating M$_{1}$-phase to an unoccupied excited state of the metallic R-phase [31].

3.B. Phase Transition Rate of Mesoscale VO$_2$

The photoinduced PT is accompanied by abrupt decrease of the total scattering signal $I_{\text{scatt}}/I_0$ within 800 fs (Fig. 5d). During this time, the film switches into metallic state. However Fig. 5d does not represent a dependence of $\tau$ on the size of VO$_2$ grains. The information about size-dependent transition rate was obtained from the angular distribution of scattered light. In order to compare $\tau$ for structures with different spatial frequencies and to exclude possible artifacts related to the polarization of the probe pulse, the scattering intensity $I_{\text{scatt}}$ was normalized and scaled between 0 and 1, with unit value for insulating (at $t=0$ fs) and zero value for metallic phase (at $t=1500$ fs) [Figs. 6 and 7a]. The normalized data is insensitive to the transient polarization anisotropy of the scattering indicatrix related to the change of the dielectric permittivity tensor, and precisely represents the map of size-dependent evolution of the VO$_2$ phase. The PT time $\tau$ is defined here as $\tau = 2\tau_2$, where $\tau_2$ is the time for the signal to drop to 0.5 value.

As can be seen from the Fig. 7a, the transient scattering signal has an oscillatory component caused by the coherent lattice vibrations [8, 15, 27, 51]. For different spatial frequencies the period and phase of the oscillations slightly vary, indicating that the coherent phonon
dynamics is likely affected by the size of VO$_2$ grains and local strain fields. As a result, a superposition of these oscillations suppresses a distinct oscillatory response in the signal of total integrated scattering (Fig. 5d).

Fig. 6 shows that the PT rate depends on spatial frequency $f$ and also on angle $\phi$. At $\phi = 0^\circ, 180^\circ$ the characteristic PT time $\tau = \tau_1 = 650$ fs weakly varies, and $\tau_2 = 325$ fs is marked in Fig. 6 by dashed line. The strongest dependence of time $\tau$ on $f$ is observed for VO$_2$ grains ordered along direction $\phi = 90^\circ, 270^\circ$, where $\tau$ varies from $\tau = 500$ fs to $\tau = 930$ fs. This result constitutes the experimental evidence of size-dependent and anisotropic PT on subpicosecond time scale for different VO$_2$ grains of the film. It is noted that the measurements were conducted at moderate laser excitation, above the PT threshold. In additional experiments it was found that an increase in optical pump shifts the characteristic PT time towards the autocorrelation width of the laser pulse, below the resolution threshold of the optical setup. In this case the grain-size-dependence and azimuthal anisotropy of measured signal vanishes.

It has to be underlined that the VO$_2$ grains with various $\tau$ values are ordered along $\phi = 90^\circ, 270^\circ$ direction, transversely to the polarization of laser pump. Moreover, no noticeable correlation was found between $\tau$ and $b_m$ or $c_m$ directions of epitaxial film. These facts indicate that the anisotropy of $\tau$ depends rather on orientation and ordering of VO$_2$ grains with respect to polarization of laser pump pulse.

The PT time depends on different parameters (i.e. laser pump pulse duration, fluence, wavelength, concentration of photoexcited carriers, nonstoichiometry, material density, band gap, defects, electron-electron and electron-phonon scattering rate, etc.). A good estimation of $\tau$ is given by Semenov in his theoretical work [29].
as
\[ \tau = \sqrt{\frac{\pi m R^2}{32 b^2}} \int_0^{\xi_0} \left[ \frac{\pi \alpha (1 - r_0) W}{2 N \hbar \omega} (\xi_0 - \xi) - \frac{\xi^2}{2} \ln \frac{\xi}{\xi_0} - \frac{\xi_0^2 - \xi^2}{4} \right] d\xi, \]

where \( N \) is the concentration of vanadium atoms, \( \alpha \) is the absorption coefficient, \( r_0 \) is the reflection coefficient, \( W \) is the pump fluence, \( m \) is the mass of vanadium atom (\( m \approx 8.5 \times 10^{-23} \text{ g} \)), \( R \) is the effective radius of electron wave function in 3d-state (\( R \approx 4.1 \times 10^{-9} \text{ cm} \)), \( \hbar \omega \) is the photon energy, \( 4b \) is the width of conduction d-band in metallic phase (\( 4b \approx 1.1 \text{ eV} \)), \( \xi \) is the order parameter with \( \xi_0 = 0.5 \) [29]. The threshold fluence \( W_c \) required to initiate the structural PT can be derived from Eq.(7) as

\[ W_c \approx \frac{0.53 \xi_0 N \hbar \omega}{\pi \alpha (1 - r_0)}. \]  

In order to calculate \( W_c \), the absorption coefficient \( \alpha = 1.8 \times 10^5 \text{ cm}^{-1} \) was obtained from transmission measurements for \( \lambda = 800 \text{ nm} \). The reflection coefficient was found as \( r_0 = 0.18 \). Using photon energy \( \hbar \omega = 1.55 \text{ eV} \) and \( N = 3 \times 10^{22} \text{ cm}^{-3} \) [53], the threshold fluence obtained with Eq.(8) is \( W_c = 4.3 \text{ mJ/cm}^2 \). This value is very close to the experimentally observed one in Refs. 7–9, 52, 54.

To support the discussion of experimental data and to provide further insight into PT dynamics we have performed a numerical calculation of \( \tau \) with the Eq.(7) versus \( \alpha \) and \( W \), assuming all other parameters are held constant. Fig. 7b shows significant dependence of time \( \tau \) on \( \alpha \) and \( W \), when laser excitation approaches the PT threshold. The calculated time \( \tau \) is found to be smaller than the experimentally observed values. Nevertheless Fig. 7b shows a fairly reasonable estimation of \( \tau \) and allows understanding the general dependence of time \( \tau \) on laser fluence and on optical absorption, which is related to the crystallinity of the film.

Fig. 7b indicates that if \( \alpha \) depends on the size of VO\(_2\) grains, the time \( \tau \) will also show grain-size-dependence. Assuming that the ultrafast PT occurs due to photoexcitation of free carriers, the variation of \( \alpha \) will result in changes in the concentration of the carriers, affecting \( \tau \). Optical birefringence of the epitaxial VO\(_2/\text{Al}_2\text{O}_3\) film provides anisotropy of \( \alpha \). Moreover, the absorption cross-section depends on shape and orientation of particles with respect to light polarization [55], which probably is the main origin of \( \tau \)-anisotropy on mesoscale. It is believed that the size-dependent PT rate is also enhanced by misfit strain in thin VO\(_2\) films, since this strain can change the birefringence of the film and \( \alpha \).

Figs. 6 and 7a show that at \( \varphi = 90^\circ \), 270\(^\circ\) the time \( \tau_2 \) shifts to its minimal value \( \tau_2 = 250 \text{ fs} \) for VO\(_2\) structures with \( f = 1.0-1.8 \mu \text{m}^{-1} \), but above \( f = 1.9 \mu \text{m}^{-1} \) it gradually increases up to \( \tau_2 = 465 \text{ fs} \), shifting from its average level (\( \tau_2 = 325 \text{ fs} \)). Taking into account data in Fig. 7b, VO\(_2\) grains with \( f > 1.9 \mu \text{m}^{-1} \) (\( d < 530 \text{ nm} \)) should have lower absorption coefficient and, therefore, longer PT time.

**4. Conclusion**

In this paper, the photoinduced insulator-to-metal phase transition and ultrafast scattering dynamics have been discussed. We show that the Gerchberg-Saxton algorithm can be applied for accurate calculation of surface autocorrelation function from angle-resolved scattering data and for partial reconstruction of PSD function. Upon light-induced PT the general patterns of the scattering indicatrix and autocorrelation function show relatively small change, since the surface geometry remains the same. Grains reorientation or film twinning was not detected on the subpicosecond time scale. However, ultrafast transformation of the dielectric permittivity tensor during first-order PT results in specific pattern of the scattering indicatrix  \( \Delta \text{BSDF}(t)/\text{BSDF}(0) \) within \( 0^\circ < \theta < 60^\circ \). This transient pattern is assigned to different structural dynamics in grains of different size, and
it emerges only after a ~300 fs delay. The autocorrelation length of the surface abruptly increases after 270 fs. This behavior is presumably a signature of stepwise PT dynamics, where the lattice transformation process is separated by several tens or hundreds femtoseconds from the laser pump instant.

Ultrafast elastic light scattering by epitaxial VO$_2$/Al$_2$O$_3$ film also reveals anisotropy of the characteristic PT time $\tau$. It noticeably increases from $\tau=650$ fs to $\tau=930$ fs for grains with sizes $d < 530$ nm, and depends on orientation of VO$_2$ grains with respect to the polarization direction of the laser pump. Numerical analysis shows that $\tau$ is likely altered by size-dependence and anisotropy of the VO$_2$ absorption coefficient.

Acknowledgements
The authors gratefully acknowledge the support from UPRM College of Arts and Sciences. N.S. was supported in part by the National Science Foundation under Grant ECCS-1139773.

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